



iCoupler[®] Digital Isolator

ADuM1100

FEATURES

- High Data Rate: DC to 100 Mbps (NRZ)
- Compatible with 3.3 V and 5.0 V Operation/
Level Translation
- 125°C Max Operating Temperature
- Low Power Operation
 - 5 V Operation
 - 1.0 mA Max @ 1 Mbps
 - 4.5 mA Max @ 25 Mbps
 - 16.8 mA Max @ 100 Mbps
 - 3.3 V Operation
 - 0.4 mA Max @ 1 Mbps
 - 3.5 mA Max @ 25 Mbps
 - 7.1 mA Max @ 50 Mbps
- 8-Lead SOIC Package (lead-free version available)
- High Common-Mode Transient Immunity: >25 kV/μs
- Safety and Regulatory Information
 - UL Recognized
 - 2500 V rms for 1 Minute per UL 1577
 - CSA Component Acceptance Notice No. 5A
 - VDE Certificate of Conformity
 - DIN EN 60747-5-2 (VDE 0884 Part 2): 2003-01
 - DIN EN 60950 (VDE 0805): 2001-12; EN 60950: 2000
 - $V_{IORM} = 560 V_{PEAK}$

APPLICATIONS

- Digital Fieldbus Isolation
- Opto-Isolator Replacement
- Computer-Peripheral Interface
- Microprocessor System Interface
- General Instrumentation and Data Acquisition Applications

GENERAL DESCRIPTION

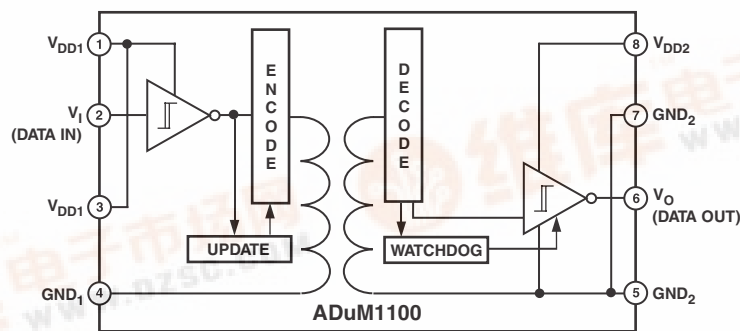
The ADuM1100 is a digital isolator based on Analog Devices' iCoupler technology. Combining high speed CMOS and monolithic air core transformer technology, this isolation component provides outstanding performance characteristics superior to alternatives such as optocoupler devices.

Configured as a pin compatible replacement for existing high speed optocouplers, the ADuM1100 supports data rates as high as 25 Mbps and 100 Mbps.

The ADuM1100 operates with either voltage supply ranging from 3.0 V to 5.5 V, boasts a propagation delay of <18 ns and edge asymmetry of <2 ns, and is compatible with temperatures up to 125°C. It operates at very low power, less than 0.9 mA of quiescent current (sum of both sides), and a dynamic current of less than 160 μA per Mbps of data rate. Unlike other optocoupler alternatives, the ADuM1100 provides dc correctness with a patented refresh feature that continuously updates the output signal.

The ADuM1100 is offered in three grades. The ADuM1100AR and ADuM1100BR can operate up to a maximum temperature of 105°C and support data rates up to 25 Mbps and 100 Mbps, respectively. The ADuM1100UR can operate up to a maximum temperature of 125°C and supports data rates up to 100 Mbps.

FUNCTIONAL BLOCK DIAGRAM



FOR PRINCIPLES OF OPERATION, SEE METHOD OF OPERATION, DC CORRECTNESS, AND MAGNETIC FIELD IMMUNITY SECTION.

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ADuM1100—SPECIFICATIONS

ELECTRICAL SPECIFICATIONS, 5 V OPERATION¹ (4.5 V ≤ V_{DD1} ≤ 5.5 V, 4.5 V ≤ V_{DD2} ≤ 5.5 V. All min/max specifications apply over the entire recommended operation range, unless otherwise noted. All typical specifications are at T_A = 25°C, V_{DD1} = V_{DD2} = 5 V.)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
DC SPECIFICATIONS						
Input Supply Current	I _{DD1(Q)}		0.3	0.8	mA	V _I = 0 V or V _{DD1}
Output Supply Current	I _{DD2(Q)}		0.01	0.06	mA	V _I = 0 V or V _{DD1}
Input Supply Current (25 Mbps) (See TPC 1)	I _{DD1(25)}		2.2	3.5	mA	12.5 MHz Logic Signal Frequency
Output Supply Current ² (25 Mbps) (See TPC 2)	I _{DD2(25)}		0.5	1.0	mA	12.5 MHz Logic Signal Frequency
Input Supply Current (100 Mbps) (See TPC 1)	I _{DD1(100)}		9.0	14	mA	50 MHz Logic Signal Frequency, ADuM1100BR/ADuM1100UR Only
Output Supply Current ² (100 Mbps) (See TPC 2)	I _{DD2(100)}		2.0	2.8	mA	50 MHz Logic Signal Frequency, ADuM1100BR/ADuM1100UR Only
Input Current	I _I	-10	+0.01	+10	μA	0 ≤ V _{IN} ≤ V _{DD1}
Logic High Output Voltage	V _{OH}	V _{DD2} - 0.1	5.0		V	I _O = -20 μA, V _I = V _{IH}
Logic Low Output Voltage	V _{OL}	V _{DD2} - 0.8	4.6		V	I _O = -4 mA, V _I = V _{IH}
			0.0	0.1	V	I _O = 20 μA, V _I = V _{IL}
			0.03	0.1	V	I _O = 400 μA, V _I = V _{IL}
			0.3	0.8	V	I _O = 4 mA, V _I = V _{IL}
SWITCHING SPECIFICATIONS						
For ADuM1100AR						
Minimum Pulse Width ³	PW			40	ns	C _L = 15 pF, CMOS Signal Levels
Maximum Data Rate ⁴		25			Mbps	C _L = 15 pF, CMOS Signal Levels
For ADuM1100BR/ADuM1100UR						
Minimum Pulse Width ³	PW		6.7	10	ns	C _L = 15 pF, CMOS Signal Levels
Maximum Data Rate ⁴		100	150		Mbps	C _L = 15 pF, CMOS Signal Levels
For All Grades						
Propagation Delay Time to Logic Low Output ^{5, 6} (See TPC 3)	t _{PHL}		10.5	18	ns	C _L = 15 pF, CMOS Signal Levels
Propagation Delay Time to Logic High Output ^{5, 6} (See TPC 3)	t _{PLH}		10.5	18	ns	C _L = 15 pF, CMOS Signal Levels
Pulse Width Distortion t _{PLH} - t _{PHL} ⁶ Change versus Temperature ⁷	PWD		0.5	2	ns	C _L = 15 pF, CMOS Signal Levels
			3		ps/°C	C _L = 15 pF, CMOS Signal Levels
Propagation Delay Skew (Equal Temperature) ^{6, 8}	t _{PSK1}			8	ns	C _L = 15 pF, CMOS Signal Levels
Propagation Delay Skew (Equal Temperature, Supplies) ^{6, 8}	t _{PSK2}			6	ns	C _L = 15 pF, CMOS Signal Levels
Output Rise/Fall Time	t _R , t _F		3		ns	C _L = 15 pF, CMOS Signal Levels
Common-Mode Transient Immunity at Logic Low/High Output ⁹	CM _L , CM _H	25	35		kV/μs	V _I = 0 or V _{DD1} , V _{CM} = 1000 V, Transient Magnitude = 800 V
Input Dynamic Power Dissipation Capacitance ¹⁰	C _{PD1}		35		pF	
Output Dynamic Power Dissipation Capacitance ¹⁰	C _{PD2}		8		pF	

See Notes on page 5.

Specifications subject to change without notice.

ELECTRICAL SPECIFICATIONS, 3.3 V OPERATION¹ (3.0 V ≤ V_{DD1} ≤ 3.6 V, 3.0 V ≤ V_{DD2} ≤ 3.6 V. All min/max specifications apply over the entire recommended operation range, unless otherwise noted. All typical specifications are at T_A = 25°C, V_{DD1} = V_{DD2} = 3.3 V.)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
DC SPECIFICATIONS						
Input Supply Current	I _{DD1(Q)}		0.1	0.3	mA	V _I = 0 V or V _{DD1}
Output Supply Current	I _{DD2(Q)}		0.005	0.04	mA	V _I = 0 V or V _{DD1}
Input Supply Current (25 Mbps) (See TPC 1)	I _{DD1(25)}		2.0	2.8	mA	12.5 MHz Logic Signal Frequency
Output Supply Current ² (25 Mbps) (See TPC 2)	I _{DD2(25)}		0.3	0.7	mA	12.5 MHz Logic Signal Frequency
Input Supply Current (50 Mbps) (See TPC 1)	I _{DD1(50)}		4.0	6.0	mA	25 MHz Logic Signal Frequency, ADuM1100BR/ADuM1100UR Only
Output Supply Current ² (50 Mbps) (See TPC 2)	I _{DD2(50)}		1.2	1.6	mA	25 MHz Logic Signal Frequency, ADuM1100BR/ADuM1100UR Only
Input Current	I _I	-10	+0.01	+10	μA	0 ≤ V _{IN} ≤ V _{DD1}
Logic High Output Voltage	V _{OH}	V _{DD2} - 0.1	3.3		V	I _O = -20 μA, V _I = V _{IH}
		V _{DD2} - 0.5	3.0		V	I _O = -2.5 mA, V _I = V _{IH}
Logic Low Output Voltage	V _{OL}		0.0	0.1	V	I _O = 20 μA, V _I = V _{IL}
			0.04	0.1	V	I _O = 400 μA, V _I = V _{IL}
			0.3	0.4	V	I _O = 2.5 mA, V _I = V _{IL}
SWITCHING SPECIFICATIONS						
For ADuM1100AR						
Minimum Pulse Width ³	PW			40	ns	C _L = 15 pF, CMOS Signal Levels
Maximum Data Rate ⁴		25			Mbps	C _L = 15 pF, CMOS Signal Levels
For ADuM1100BR/ADuM1100UR						
Minimum Pulse Width ³	PW		10	20	ns	C _L = 15 pF, CMOS Signal Levels
Maximum Data Rate ⁴		50	100		Mbps	C _L = 15 pF, CMOS Signal Levels
For All Grades						
Propagation Delay Time to Logic Low Output ^{5, 6} (See TPC 4)	t _{PHL}		14.5	28	ns	C _L = 15 pF, CMOS Signal Levels
Propagation Delay Time to Logic High Output ^{5, 6} (See TPC 4)	t _{PLH}		15.0	28	ns	C _L = 15 pF, CMOS Signal Levels
Pulse Width Distortion t _{PLH} - t _{PHL} ⁶ Change versus Temperature ⁷	PWD		0.5	3	ns	C _L = 15 pF, CMOS Signal Levels
Propagation Delay Skew (Equal Temperature) ^{6, 8}	t _{PSK1}			15	ns	C _L = 15 pF, CMOS Signal Levels
Propagation Delay Skew (Equal Temperature, Supplies) ^{6, 8}	t _{PSK2}			12	ns	C _L = 15 pF, CMOS Signal Levels
Output Rise/Fall Time	t _R , t _F		3		ns	C _L = 15 pF, CMOS Signal Levels
Common-Mode Transient Immunity at Logic Low/High Output ⁹	CM _L , CM _H	25	35		kV/μs	V _I = 0 or V _{DD1} , V _{CM} = 1000 V, Transient Magnitude = 800 V
Input Dynamic Power Dissipation Capacitance ¹⁰	C _{PD1}		47		pF	
Output Dynamic Power Dissipation Capacitance ¹⁰	C _{PD2}		14		pF	

See Notes on page 5.

Specifications subject to change without notice.

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ELECTRICAL SPECIFICATIONS, MIXED 5 V/3 V or 3 V/5 V OPERATION¹ (5 V/3 V operation: $4.5\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$, $3.0\text{ V} \leq V_{DD2} \leq 3.6\text{ V}$.

3 V/5 V operation: $3.0\text{ V} \leq V_{DD1} \leq 3.6\text{ V}$, $4.5\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$. All min/max specifications apply over the entire recommended operation range, unless otherwise noted. All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = 3.3\text{ V}$, $V_{DD2} = 5\text{ V}$ or $V_{DD1} = 5\text{ V}$, $V_{DD2} = 3.3\text{ V}$.)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
DC SPECIFICATIONS						
Input Supply Current, Quiescent	$I_{DDI(Q)}$		0.3	0.8	mA	
5 V/3 V Operation			0.1	0.3	mA	
Output Supply Current, Quiescent	$I_{DDO(Q)}$		0.005	0.04	mA	
5 V/3 V Operation			0.01	0.06	mA	
Input Supply Current, 25 Mbps	$I_{DDI(25)}$		2.2	3.5	mA	12.5 MHz Logic Signal Frequency
5 V/3 V Operation			2.0	2.8	mA	12.5 MHz Logic Signal Frequency
Output Supply Current, 25 Mbps	$I_{DDO(25)}$		0.3	0.7	mA	12.5 MHz Logic Signal Frequency
5 V/3 V Operation			0.5	1.0	mA	12.5 MHz Logic Signal Frequency
Input Supply Current, 50 Mbps	$I_{DDI(50)}$		4.5	7.0	mA	25 MHz Logic Signal Frequency
5 V/3 V Operation			4.0	6.0	mA	25 MHz Logic Signal Frequency
Output Supply Current, 50 Mbps	$I_{DDO(50)}$		1.2	1.6	mA	25 MHz Logic Signal Frequency
5 V/3 V Operation			1.0	1.5	mA	25 MHz Logic Signal Frequency
Input Currents	I_{IA}	-10	+0.01	+10	μA	$0 \leq V_{IA}, V_{IB}, V_{IC}, V_{ID} \leq V_{DD1}$ or V_{DD2}
Logic High Output Voltage,	V_{OH}	$V_{DD2} - 0.1$	3.3		V	$I_O = -20\text{ }\mu\text{A}$, $V_I = V_{IH}$
5 V/3 V Operation		$V_{DD2} - 0.5$	3.0		V	$I_O = -2.5\text{ mA}$, $V_I = V_{IH}$
Logic Low Output Voltage,	V_{OL}		0.0	0.1	V	$I_O = 20\text{ }\mu\text{A}$, $V_I = V_{IL}$
5 V/3 V Operation			0.04	0.1	V	$I_O = 400\text{ }\mu\text{A}$, $V_I = V_{IL}$
			0.3	0.4	V	$I_O = 2.5\text{ mA}$, $V_I = V_{IL}$
Logic High Output Voltage,	V_{OH}	$V_{DD2} - 0.1$	5.0		V	$I_O = -20\text{ }\mu\text{A}$, $V_I = V_{IH}$
3 V/5 V Operation		$V_{DD2} - 0.8$	4.6		V	$I_O = -4\text{ mA}$, $V_I = V_{IH}$
Logic Low Output Voltage,	V_{OL}		0.0	0.1	V	$I_O = 20\text{ }\mu\text{A}$, $V_I = V_{IL}$
3 V/5 V Operation			0.03	0.1	V	$I_O = 400\text{ }\mu\text{A}$, $V_I = V_{IL}$
			0.3	0.8	V	$I_O = 4\text{ mA}$, $V_I = V_{IL}$
SWITCHING SPECIFICATIONS						
For ADuM1100AR						
Minimum Pulse Width ³	PW			40	ns	$C_L = 15\text{ pF}$, CMOS Signal Levels
Maximum Data Rate ⁴		25			Mbps	$C_L = 15\text{ pF}$, CMOS Signal Levels
For ADuM1100BR/ADuM1100UR						
Minimum Pulse Width ³	PW			20	ns	$C_L = 15\text{ pF}$, CMOS Signal Levels
Maximum Data Rate ⁴		50			Mbps	$C_L = 15\text{ pF}$, CMOS Signal Levels
For All Grades						
Propagation Delay Time to Logic	t_{PHL}, t_{PLH}					
Low/High Output ^{5, 6}						
5 V/3 V Operation (See TPC 5)			13	21	ns	$C_L = 15\text{ pF}$, CMOS Signal Levels
3 V/5 V Operation (See TPC 6)			16	26	ns	$C_L = 15\text{ pF}$, CMOS Signal Levels
Pulse Width Distortion, $ t_{PLH} - t_{PHL} $ ⁶	PWD					
5 V/3 V Operation				0.5	2	ns
3 V/5 V Operation			0.5	3	ns	$C_L = 15\text{ pF}$, CMOS Signal Levels
Change versus Temperature						
5 V/3 V Operation			3		ps/ $^\circ\text{C}$	$C_L = 15\text{ pF}$, CMOS Signal Levels
3 V/5 V Operation			10		ps/ $^\circ\text{C}$	$C_L = 15\text{ pF}$, CMOS Signal Levels
Propagation Delay Skew	t_{PSK1}					
(Equal Temperature) ^{6, 8}						
5 V/3 V Operation				12	ns	$C_L = 15\text{ pF}$, CMOS Signal Levels
3 V/5 V Operation				15	ns	$C_L = 15\text{ pF}$, CMOS Signal Levels

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
SWITCHING SPECIFICATIONS (continued)						
Propagation Delay Skew (Equal Temperature, Supplies) ^{6, 8}	t_{PSK2}			9	ns	$C_L = 15$ pF, CMOS Signal Levels
5 V/3 V Operation				12	ns	
3 V/5 V Operation					ns	
Output Rise/Fall Time (10% to 90%)	t_R, t_f		3			$C_L = 15$ pF, CMOS Signal Levels
Common-Mode Transient Immunity at Logic Low/High Output ⁸	$ CM_L ,$ $ CM_H $	25	35		kV/ μ s	$V_I = 0$ or V_{DD1} , $V_{CM} = 1000$ V, Transient Magnitude = 800 V
Input Dynamic Power Dissipation Capacitance ¹⁰	C_{PD1}					
5 V/3 V Operation			35		pF	
3 V/5 V Operation			47		pF	
Output Dynamic Power Dissipation Capacitance ¹⁰	C_{PD2}					
5 V/3 V Operation			8		pF	
3 V/5 V Operation			14		pF	

NOTES

- ¹All voltages are relative to their respective ground.
- ²Output supply current values are with no output load present. The supply current drawn at a given signal frequency when an output load is present is given by $I_{DD2(L)} = I_{DD2} + V_{DD2} \times f \times C_L$, where I_{DD2} is the unloaded output supply current, f is the input signal frequency, and C_L is the output load capacitance.
- ³The minimum pulse width is the shortest pulse width at which the specified pulse width distortion is guaranteed.
- ⁴The maximum data rate is the fastest data rate at which the specified pulse width distortion is guaranteed.
- ⁵ t_{PHL} is measured from the 50% level of the falling edge of the V_I signal to the 50% level of the falling edge of the V_O signal. t_{PLH} is measured from the 50% level of the rising edge of the V_I signal to the 50% level of the rising edge of the V_O signal.
- ⁶Since the input thresholds of the ADuM1100 are at voltages other than the 50% level of typical input signals, the measured propagation delay and pulse width distortion may be affected by slow input rise/fall times. See the Propagation Delay-Related Parameters section and Figures 3 to 7 for information on the impact of given input rise/fall times on these parameters.
- ⁷Pulse width distortion change versus temperature is the absolute value of the change in pulse width distortion for a 1°C change in operating temperature.
- ⁸ t_{PSK1} is the magnitude of the worst-case difference in t_{PHL} and/or t_{PLH} that will be measured between units at the same operating temperature and output load within the recommended operating conditions. t_{PSK2} is the magnitude of the worst-case difference in t_{PHL} and/or t_{PLH} that will be measured between units at the same operating temperature, supply voltages, and output load within the recommended operating conditions.
- ⁹ CM_H is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_O > 0.8 V_{DD2}$. CM_L is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_O < 0.8$ V. The common-mode voltage slew rates apply to both rising and falling edges. The transient magnitude is the range over which the common-mode is slewed.
- ¹⁰The dynamic power dissipation capacitance is given by $C_{PDi} = (I_{DDi(100)} - I_{DDi(Q)}) / (V_{DDi} \times f)$, where $i = 1$ or 2 and f is the input signal frequency. The supply current consumptions at a given frequency and output load are calculated as $I_{DD1} = C_{PD1} \times V_{DD1} \times f + I_{DD1(Q)}$; $I_{DD2(L)} = (C_{PD2} + C_L) \times V_{DD2} \times f + I_{DD2(Q)}$, where C_L is the output load capacitance.

Specifications subject to change without notice.

PACKAGE CHARACTERISTICS

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Resistance (Input-Output) ¹	R_{I-O}		10^{12}		Ω	$f = 1$ MHz
Capacitance (Input-Output) ¹	C_{I-O}		1		pF	
Input Capacitance ²	C_I		4.0		pF	Thermocouple Located at Center Underside of Package
Input IC Junction-to-Case Thermal Resistance	θ_{JCI}		46		°C/W	
Output IC Junction-to-Case Thermal Resistance	θ_{JCO}		41		°C/W	
Package Power Dissipation	P_{PD}			240	mW	

NOTES

- ¹Device considered a 2-terminal device: Pins 1, 2, 3, and 4 shorted together and Pins 5, 6, 7, and 8 shorted together.
- ²Input capacitance is measured at Pin 2 (V_I).

ADuM1100

REGULATORY INFORMATION

The ADuM1100 has been approved by the following organizations:

UL	CSA	VDE
Recognized under 1577 Component Recognition Program ¹ File E214100	Approved under CSA Component Acceptance Notice No. 5A, C22.2 No. 1-98, C22.2 No. 14-95, and C22.2 No. 950-95 File 205078	Certified according to DIN EN 60747-5-2 (VDE 0884 Part 2): 2003-1 ² DIN EN 60950 (VDE 0805): 2001-12; EN60950: 2000 File 2471900-4880-0002

NOTES

¹In accordance with UL 1577, each ADuM1100 is proof tested by applying an insulation test voltage ≥ 3000 V rms for 1 second (leakage detection current limit, $I_{L-O} \leq 5 \mu\text{A}$).

²In accordance with DIN EN 60747-5-2, each ADuM1100 is proof tested by applying an insulation test voltage ≥ 1050 V_{PEAK} for 1 second (partial discharge detection limit ≤ 5 pC). A “*” mark branded on the component designates DIN EN 60747-5-2 approval.

INSULATION AND SAFETY-RELATED SPECIFICATIONS

Parameter	Symbol	Value	Unit	Conditions
Minimum External Air Gap (Clearance)	L(I01)	4.90 min	mm	Measured from input terminals to output terminals, shortest distance through air
Minimum External Tracking (Creepage)	L(I02)	4.01 min	mm	Measured from input terminals to output terminals, shortest distance path along body
Minimum Internal Gap (Internal Clearance)		0.016 min	mm	Insulation distance through insulation
Tracking Resistance (Comparative Tracking Index)	CTI	>175	V	DIN IEC 112/VDE 0303 Part 1
Isolation Group		IIIa		Material Group (DIN VDE 0110, 1/89, Table 1)

DIN EN 60747-5-2 (VDE 0884 Part 2) INSULATION CHARACTERISTICS

Description	Symbol	Characteristic	Unit
Installation Classification per DIN VDE 0110 For Rated Mains Voltage ≤ 150 V rms For Rated Mains Voltage ≤ 300 V rms For Rated Mains Voltage ≤ 400 V rms		I to IV I to III I to II	
Climatic Classification ADuM1100AR and ADuM1100BR ADuM1100UR		40/105/21 40/125/21	
Pollution Degree (DIN VDE 0110, Table I)		2	
Maximum Working Insulation Voltage	V _{IORM}	560	V _{PEAK}
Input-to-Output Test Voltage, Method b1 $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test, $t_M = 1$ sec, Partial Discharge < 5 pC	V _{PR}	1050	V _{PEAK}
Input-to-Output Test Voltage, Method a After Environmental Tests Subgroup 1	V _{PR}	672	V _{PEAK}
$V_{IORM} \times 1.6 = V_{PR}$, $t_M = 10$ sec, Partial Discharge < 5 pC After Input and/or Output Safety Test Subgroup 2/3	V _{PR}	896	V _{PEAK}
$V_{IORM} \times 1.2 = V_{PR}$, $t_M = 10$ sec, Partial Discharge < 5 pC	V _{PR}	672	V _{PEAK}
Highest Allowable Overvoltage (Transient Overvoltage, $t_{NI} = 60$ sec)	V _{TR}	4000	V _{PEAK}
Safety-Limiting Values (Maximum Value Allowed in the Event of a Failure, See Thermal Derating Curve, Figure 1 Case Temperature	T _S	150	°C
Input Current	I _{S, INPUT}	160	mA
Output Current	I _{S, OUTPUT}	170	mA
Insulation Resistance at T _S , V _{IO} = 500 V	R _S	$>10^9$	Ω

This isolator is suitable for basic isolation only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits.

The * marking on the package denotes DIN EN 60747-5-2 approval for 560 V_{PEAK} working voltage.

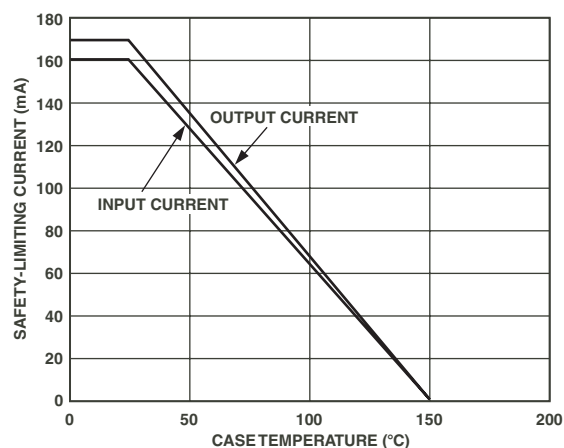


Figure 1. Thermal Derating Curve, Dependence of Safety-Limiting Values with Case Temperature per DIN EN 60747-5-2

ABSOLUTE MAXIMUM RATINGS¹

Parameter	Symbol	Min	Max	Unit
Storage Temperature	T_{ST}	-55	+150	°C
Ambient Operating Temperature	T_A	-40	+125	°C
Supply Voltages ²	V_{DD1}, V_{DD2}	-0.5	+6.5	V
Input Voltage ²	V_I	-0.5	$V_{DD1} + 0.5$	V
Output Voltage ²	V_O	-0.5	$V_{DD2} + 0.5$	V
Average Current, per Pin ³				
Temperature $\leq 105^\circ\text{C}$		-25	+25	mA
Temperature $\leq 125^\circ\text{C}$				
Input Current		-7	+7	mA
Output Current		-20	+20	mA
Common-Mode Transients ⁴		-100	+100	kV/ μs

NOTES

¹ Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only. Functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions may affect device reliability. Ambient temperature = 25°C, unless otherwise noted.

² All voltages are relative to their respective ground.

³ See Figure 1 for information on maximum allowable current for various temperatures.

⁴ Refers to common-mode transients across the insulation barrier. Common-mode transients exceeding the Absolute Maximum Rating may cause latch-up or permanent damage.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Max	Unit
Operating Temperature				
ADuM1100AR and ADuM1100BR	T_A	-40	+105	°C
ADuM1100UR	T_A	-40	+125	°C
Supply Voltages ¹	V_{DD1}, V_{DD2}	3.0	5.5	V
Logic High Input Voltage, 5 V Operation ^{1,2} (See TPCs 7 and 8)	V_{IH}	2.0	V_{DD1}	V
Logic Low Input Voltage, 5 V Operation ^{1,2} (See TPCs 7 and 8)	V_{IL}	0.0	0.8	V
Logic High Input Voltage, 3.3 V Operation ^{1,2} (See TPCs 7 and 8)	V_{IH}	1.5	V_{DD1}	V
Logic Low Input Voltage, 3.3 V Operation ^{1,2} (See TPCs 7 and 8)	V_{IL}	0.0	0.5	V
Input Signal Rise and Fall Times			1.0	ms

NOTES

¹All voltages are relative to their respective ground.

²Input switching thresholds have 300 mV of hysteresis.

See the Method of Operation, DC Correctness, and Magnetic Field Immunity section and Figures 8 and 9 for information on immunity to external magnetic fields.

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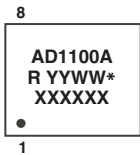
Table I. Truth Table (Positive Logic)

V _I Input	V _{DD1} State	V _{DD2} State	V _O Output
H	Powered	Powered	H
L	Powered	Powered	L
X	Unpowered	Powered	H*
X	Powered	Unpowered	X*

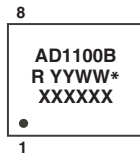
*V_O returns to V_I state within 1 μs of power restoration.

Note: Package branding is as follows:

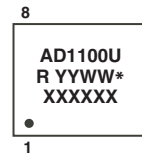
ADuM1100AR,
ADuM1100AR-RL7



ADuM1100BR,
ADuM1100BR-RL7



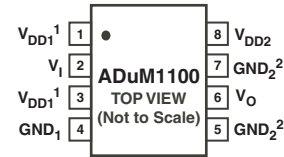
ADuM1100UR,
ADuM1100UR-RL7



where:

- * = DIN EN 60747-5-2 mark
- R = Package Designator (R denotes SOIC)
- YYWW = Date Code
- XXXXXX = Lot Code

PIN CONFIGURATION



NOTES

- ¹PIN 1 AND PIN 3 ARE INTERNALLY CONNECTED. EITHER OR BOTH MAY BE USED FOR V_{DD1}.
- ²PIN 5 AND PIN 7 ARE INTERNALLY CONNECTED. EITHER OR BOTH MAY BE USED FOR GND₂.

ORDERING GUIDE

Model	Temperature Range	Max Data Rate (Mbps)	Min Pulse Width (ns)	Package Description	Package Option
ADuM1100AR	-40°C to +105°C	25	40	8-Lead SOIC	R-8
ADuM1100AR-RL7	-40°C to +105°C	25	40	8-Lead SOIC, 1,000 Piece Reel	R-8
ADuM1100ARZ*	-40°C to +105°C	25	40	8-Lead SOIC	R-8
ADuM1100ARZ-RL7*	-40°C to +105°C	25	40	8-Lead SOIC, 1,000 Piece Reel	R-8
ADuM1100BR	-40°C to +105°C	100	10	8-Lead SOIC	R-8
ADuM1100BR-RL7	-40°C to +105°C	100	10	8-Lead SOIC, 1,000 Piece Reel	R-8
ADuM1100BRZ*	-40°C to +105°C	100	10	8-Lead SOIC	R-8
ADuM1100BRZ-RL7*	-40°C to +105°C	100	10	8-Lead SOIC, 1,000 Piece Reel	R-8
ADuM1100UR	-40°C to +125°C	100	10	8-Lead SOIC	R-8
ADuM1100UR-RL7	-40°C to +125°C	100	10	8-Lead SOIC, 1,000 Piece Reel	R-8
ADuM1100URZ*	-40°C to +125°C	100	10	8-Lead SOIC	R-8
ADuM1100URZ-RL7*	-40°C to +125°C	100	10	8-Lead SOIC, 1,000 Piece Reel	R-8
ADuM1100EVAL				Evaluation Board	

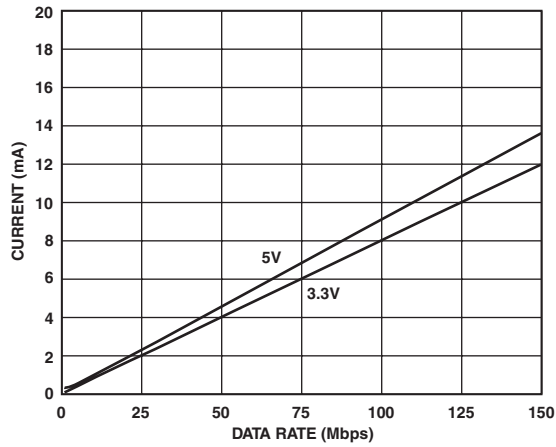
*Z = Lead Free

CAUTION

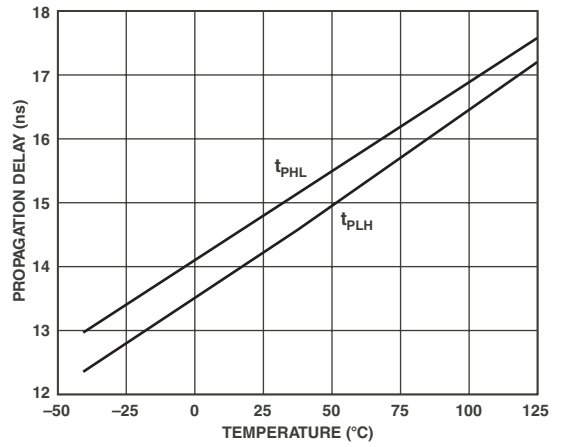
ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the ADuM1100 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



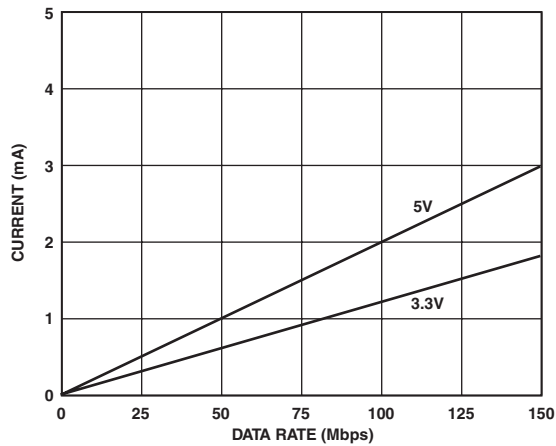
Typical Performance Characteristics—ADuM1100



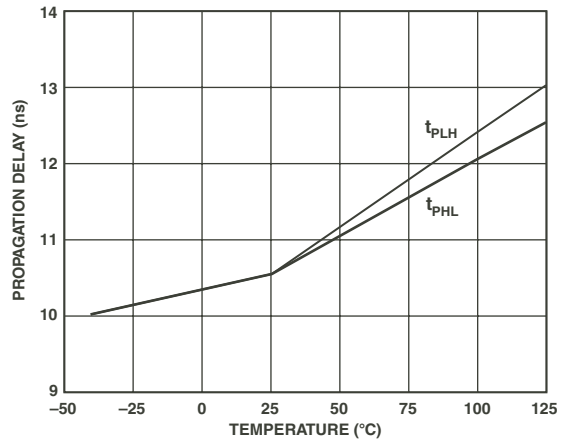
TPC 1. Typical Input Supply Current vs. Logic Signal Frequency for 5 V and 3.3 V Operation



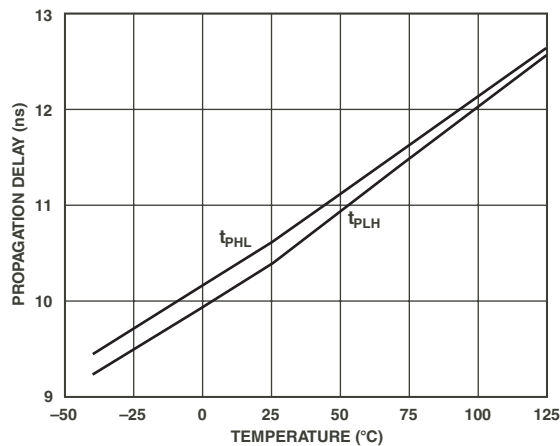
TPC 4. Typical Propagation Delays vs. Temperature, 3.3 V Operation



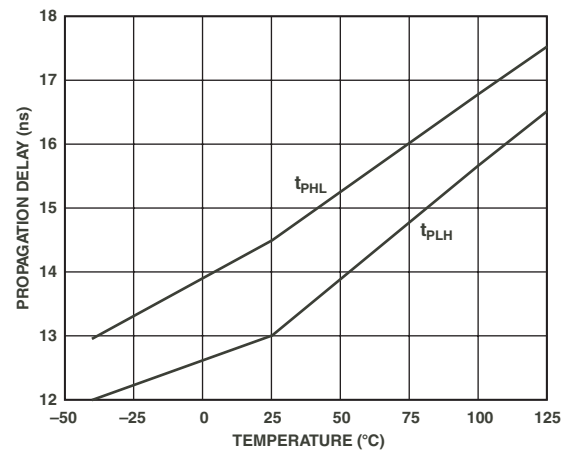
TPC 2. Typical Output Supply Current vs. Logic Signal Frequency for 5 V and 3.3 V Operation



TPC 5. Typical Propagation Delays vs. Temperature, 5 V/3 V Operation

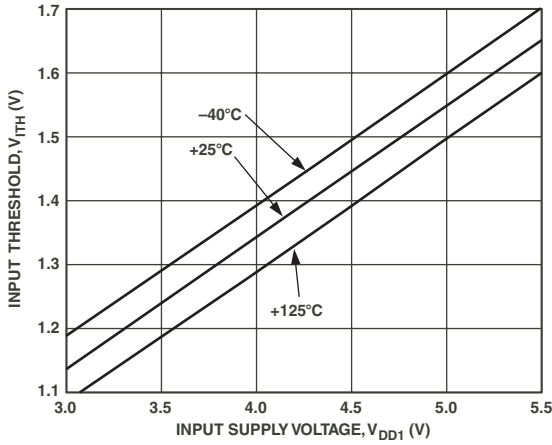


TPC 3. Typical Propagation Delays vs. Temperature, 5 V Operation

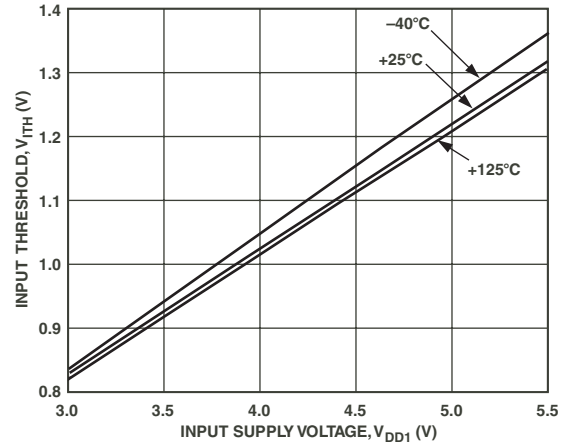


TPC 6. Typical Propagation Delays vs. Temperature, 3 V/5 V Operation

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TPC 7. Typical Input Voltage Switching Threshold, Low-to-High Transition



TPC 8. Typical Input Voltage Switching Threshold, High-to-Low Transition

APPLICATION INFORMATION

PC Board Layout

The ADuM1100 digital isolator requires no external interface circuitry for the logic interfaces. A bypass capacitor is recommended at the input and output supply pins. The input bypass capacitor may most conveniently be connected between Pins 3 and 4 (Figure 2). Alternatively, the bypass capacitor may be located between Pins 1 and 4. The output bypass capacitor may be connected between Pins 7 and 8 or Pins 5 and 8. The capacitor value should be between 0.01 μ F and 0.1 μ F. The total lead length between both ends of the capacitor and the power supply pins should not exceed 20 mm.

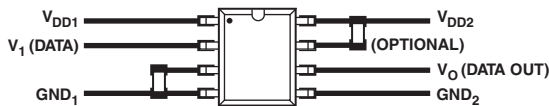


Figure 2. Recommended Printed Circuit Board Layout

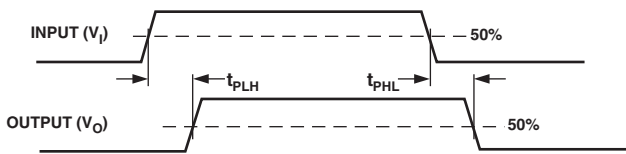


Figure 3. Propagation Delay Parameters

Propagation Delay-Related Parameters

Propagation delay time describes the length of time it takes for a logic signal to propagate through a component. Propagation delay

time to logic low output and propagation delay time to logic high output refer to the duration between an input signal transition and the respective output signal transition (Figure 3).

Pulse width distortion is the maximum difference between t_{PLH} and t_{PHL} and provides an indication of how accurately the input signal's timing is preserved in the component's output signal. Propagation delay skew is the difference between the minimum and maximum propagation delay values among multiple ADuM1100 components operated at the same operating temperature and having the same output load.

Depending on the input signal rise/fall time, the measured propagation delay based on the input 50% level can vary from the true propagation delay of the component (as measured from its input switching threshold). This is due to the fact that the input threshold, as is the case with commonly used optocouplers, is at a different voltage level than the 50% point of typical input signals. This propagation delay difference is given by

$$\Delta_{LH} = t'_{PLH} - t_{PLH} = (t_r / 0.8V_I) (0.5V_I - V_{ITH(L-H)})$$

$$\Delta_{HL} = t'_{PHL} - t_{PHL} = (t_f / 0.8V_I) (0.5V_I - V_{ITH(H-L)})$$

where:

t_{PLH} , t_{PHL} = propagation delays as measured from the input 50% level.

t'_{PLH} , t'_{PHL} = propagation delays as measured from the input switching thresholds.

t_r , t_f = input 10% to 90% rise/fall time.

V_I = amplitude of input signal (0 to V_I levels assumed).

$V_{ITH(L-H)}$, $V_{ITH(H-L)}$ = input switching thresholds.

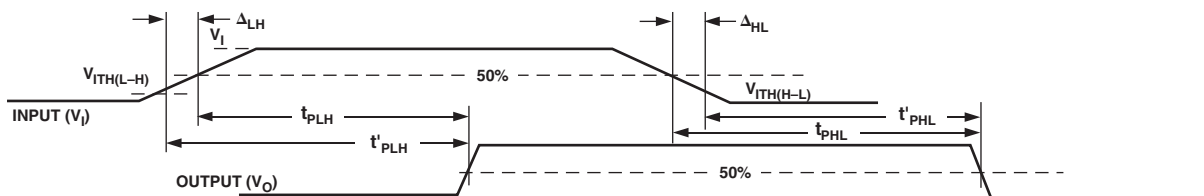


Figure 4. Impact of Input Rise/Fall Time on Propagation Delay

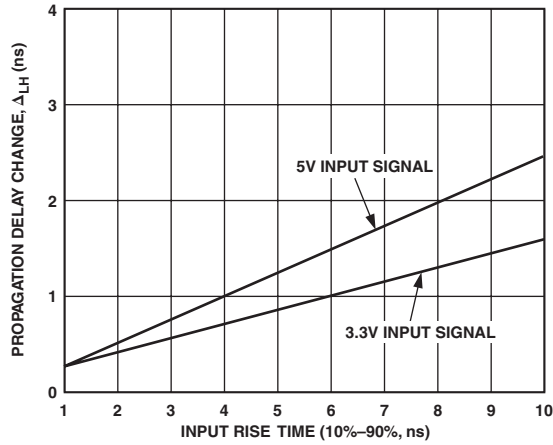


Figure 5. Typical Propagation Delay Change due to Input Rise Time Variation (for $V_{DD1} = 3.3\text{ V}$ and 5 V)

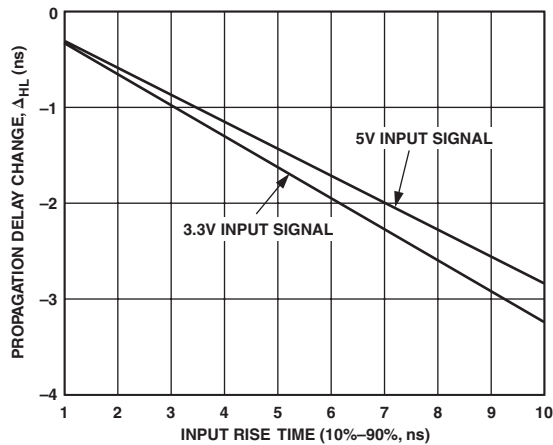


Figure 6. Typical Propagation Delay Change due to Input Fall Time Variation (for $V_{DD1} = 3.3\text{ V}$ and 5 V)

The impact of the slower input edge rates can also affect the measured pulse width distortion as based on the input 50% level. This impact may either increase or decrease the apparent pulse width distortion depending on the relative magnitudes of t_{PHL} , t_{PLH} , and PWD. The case of interest here is the condition that leads to the largest increase in pulse width distortion. The change in this case is given by

$$\Delta_{PWD} = PWD' - PWD = \Delta_{LH} - \Delta_{HL} = (t/0.8V_1) \left(V - V_{ITH(L-H)} - V_{ITH(H-L)} \right), \text{ (for } t = t_r = t_f \text{)}$$

where:

$$PWD = |t_{PLH} - t_{PHL}|$$

$$PWD' = |t'_{PLH} - t'_{PHL}|$$

This adjustment in pulse width distortion is plotted as a function of input rise/fall time in Figure 7.

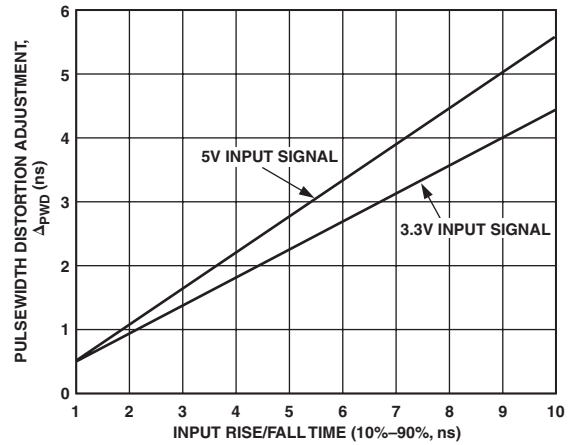


Figure 7. Typical Pulse Width Distortion Adjustment due to Input Rise/Fall Time Variation (at $V_{DD1} = 3.3\text{ V}$ and 5 V)

Method of Operation, DC Correctness, and Magnetic Field Immunity

Referring to the functional block diagram, the two coils act as a pulse transformer. Positive and negative logic transitions at the isolator input cause narrow (2 ns) pulses to be sent via the transformer to the decoder. The decoder is bistable and therefore either set or reset by the pulses indicating input logic transitions. In the absence of logic transitions at the input for more than 2 μs , a periodic update pulse of the appropriate polarity is sent to ensure dc correctness at the output. If the decoder receives none of these update pulses for more than about 5 μs , the input side is assumed to be unpowered or nonfunctional, in which case the isolator output is forced to a logic high state by the watchdog timer circuit.

The limitation on the ADuM1100's magnetic field immunity is set by the condition in which induced voltage in the transformer's receiving coil is sufficiently large to either falsely set or reset the decoder. The analysis that follows defines the conditions under which this may occur. The ADuM1100's 3.3 V operating condition is examined because it represents the most susceptible mode of operation.

The pulses at the transformer output are greater than 1.0 V in amplitude. The decoder has sensing thresholds at about 0.5 V, therefore establishing a 0.5 V margin in which induced voltages can be tolerated. The induced voltage induced across the receiving coil is given by

$$V = (-d\beta/dt) \Sigma \pi r_n^2; n = 1, 2, \dots, N$$

where:

β = magnetic flux density (Gauss).

N = number of turns in receiving coil.

r_n = radius of n th turn in receiving coil (cm).

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Given the geometry of the receiving coil in the ADuM1100 and an imposed requirement that the induced voltage be at most 50% of the 0.5 V margin at the decoder, a maximum allowable magnetic field is calculated as shown in Figure 8.

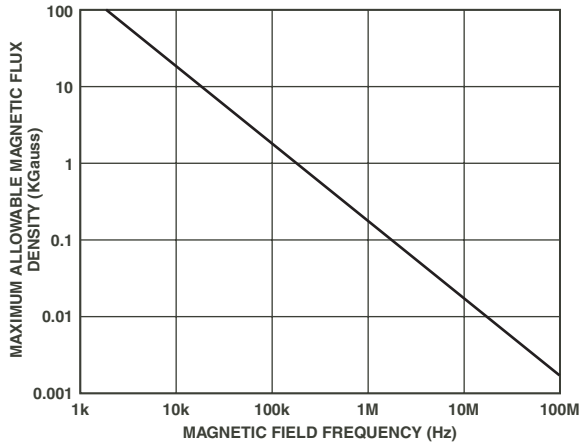


Figure 8. Maximum Allowable External Magnetic Field

For example, at a magnetic field frequency of 1 MHz, the maximum allowable magnetic field of 0.2 K Gauss induces a voltage of 0.25 V at the receiving coil. This is about 50% of the sensing threshold and will not cause a faulty output transition. Similarly, if such an event were to occur during a transmitted pulse (and was of the worst-case polarity), it would reduce the received pulse from >1.0 V to 0.75 V—still well above the 0.5 V sensing threshold of the decoder.

The preceding magnetic flux density values correspond to specific current magnitudes at given distances away from the ADuM1100 transformers. Figure 9 expresses these allowable current magnitudes as a function of frequency for selected distances. As can be seen, the ADuM1100 is extremely immune and can be affected only by extremely large currents operated at high frequency and very close to the component. For the 1 MHz example noted, one would have to place a current of 0.5 kA 5 mm away from the ADuM1100 to affect the component's operation.

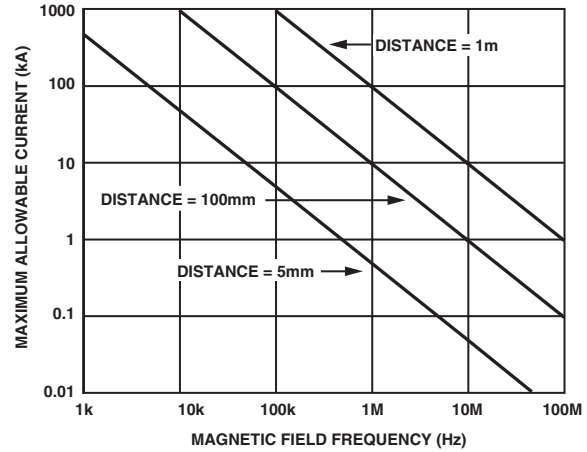


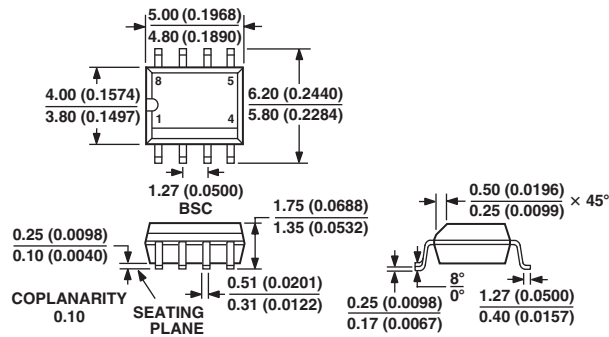
Figure 9. Maximum Allowable Current for Various Current-to-ADuM1100 Spacings

Note that at combinations of strong magnetic field and high frequency, any loops formed by printed circuit board traces could induce sufficiently large error voltages to trigger the thresholds of succeeding circuitry. Care should be taken in the layout of such traces to avoid this possibility.

OUTLINE DIMENSIONS

8-Lead Standard Small Outline Package [SOIC]
Narrow Body
(R-8)

Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MS-012AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

ADuM1100

Revision History

Location	Page
10/03—Data Sheet changed from REV. D to REV. E.	
Changes to Product Name	1
Changes to FEATURES	1
Changes to GENERAL DESCRIPTION	1
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Changes to DIN EN 60747-5-2 (VDE 0884 Part 2) INSULATION CHARACTERISTICS	6
Changes to ABSOLUTE MAXIMUM RATINGS	7
Changes to RECOMMENDED OPERATING CONDITIONS	7
Changes to ORDERING GUIDE	8
6/03—Data Sheet changed from REV. C to REV. D.	
Changed DIN EN 60747-5-2 (VDE 0884 Part 2) INSULATION CHARACTERISTICS	6
Updated ORDERING GUIDE	8
Updated OUTLINE DIMENSIONS	13
4/03—Data Sheet changed from REV. B to REV. C.	
Changes to FEATURES	1
Changes to Patent note	1
Changes to REGULATORY INFORMATION	6
Changes to INSULATION CHARACTERISTICS section	6
Changes to ABSOLUTE MAXIMUM RATINGS	7
Changes to Package Branding	8
Changes to Method of Operation, DC Correctness, and Magnetic Field Immunity section	11
Replaced Figure 9	12
1/03—Data Sheet changed from REV. A to REV. B.	
Added ADuM1100UR Grade	Universal
Changed ADuM1100AR/ADuM1100BR to ADuM1100	Universal
Changes to FEATURES	1
Changes to GENERAL DESCRIPTION	1
Changes to SPECIFICATIONS	2
Added Electrical Specifications, Mixed 5 V/3 V or 3 V/5 V Operation table	4
Updated REGULATORY INFORMATION	6
Changes to VDE 0884 INSULATION CHARACTERISTICS	6
Changes to ABSOLUTE MAXIMUM RATINGS	7
Changes to Package Branding	8
Updated TPCs 3–8	9
Deleted <i>i</i> Coupler in Field Bus Networks section	11
Changes to Figure 8	12
Added a new Figure 9 and related text	12
11/02—Data Sheet changed from REV. 0 to REV. A.	
Edits to FEATURES	1
Edits to REGULATORY INFORMATION	4
Edits to VDE 0884 INSULATION CHARACTERISTICS	5
Added Revision History	12
Updated OUTLINE DIMENSIONS	12

